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R928, R955

Extended Red, High Sensitivity, Multialkali Photocathode 28 mm (1-1/8 Inch) Diameter, 9-Stage, Side-On Type

The R928 and R955 feature extremely high quantum efficiency, high current amplification, good S/N ratio and wide spectral response from UV to near infrared. The R928 employs a UV glass envelope and the R955 has a fused silica envelope for UV sensitivity extension.

The R928 and R955 are well suited for use in broad-band spectrophotometers, atomic absorption spectrophotometers, emission spectrophotometers and other precision photometric instruments.

FEATURES

185 nm to 900 nm
160 nm to 900 nm
250 μA/lm
74 mA/W
2500 A/Im
7.4 × 10 ⁵ A/W

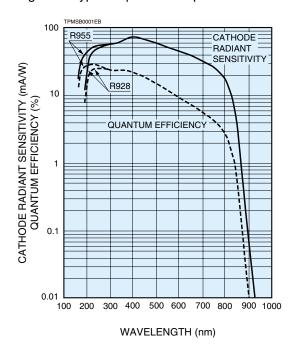


SPECIFICATIONS

GENERAL

Pa	rameter	Description/Value	Unit
Spectral	R928	185 to 900	nm
Response	R955	160 to 900	nm
Wavelength of	Maximum Response	400	nm
Photocathode	Material	Multialkali	
Tholocalhode	Minimum Effective Area	8 × 24	mm
Window	R928	UV glass	_
Material	R955	Fused silica	_
	Secondary Emitting Surface	Multialkali	_
Dynode	Structure	Circular-cage	_
	Number of Stages	9	_
Direct Interelectrode	Anode to Last Dynode	4	pF
Capacitances	Anode to All Other Electrodes	6	pF
Base		11-pin base JEDEC No. B11-88	_
Weight		Approx. 45	g
Operating Amb	ient Temperature	-30 to +50	°C
Storage Tempe	erature	-30 to +50	°C
Suitable Socke	t	E678–11A (Sold Separately)	
Suitable Socke	t Accombly	E717-63 (Sold Separately)	
Sullable Socke	it Assembly	E717–74 (Sold Separately)	

Figure 1: Typical Spectral Response



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PHOTOMULTIPLIER TUBES R928, R955

MAXIMUM RATINGS (Absolute Maximum Values)

	Parameter	Value	Unit
Supply Voltage	Between Anode and Cathode	1250	V
	Between Anode and Last Dynode	250	٧
Average Anode Curr	rent ^A	0.1	mA

CHARACTERISTICS (at 25 °C)

		R928			R955		Unit		
	Parameter		Min.	Тур.	Max.	Min.	Тур.	Max.	Ullit
	Quantum Efficien (at Peak Wavelen	•	_	25.4 (at 260 nm)	_	_	29.0 (at 220 nm)	_	%
	Luminous B		140	250	_	140	250	_	μA/lm
		at 194 nm	_	18	_	_	43	_	mA/W
Cathada Canaitivity		at 254 nm	_	52	_	_	56	_	mA/W
Cathode Sensitivity	Radiant	at 400 nm	_	74	_	_	74	_	mA/W
		at 633 nm	_	41	_	_	41	_	mA/W
		at 852 nm	_	3.5	_	_	3.5	_	mA/W
	Red/White Ratio		0.2	0.3	_	0.2	0.3	_	_
	Blue Sensitivity Ir	ndex ^D	_	8	_	_	8	_	_
	Luminous ^E		400	2500	_	400	2500	_	A/Im
	Radiant	at 194 nm	_	1.8×10^{5}	_	_	4.3×10^{5}	_	A/W
Anode Sensitivity		at 254 nm	_	5.2×10^{5}	_	_	5.6×10^{5}	_	A/W
Arioue Serisitivity		at 400 nm	_	7.4×10^{5}	_	_	7.4×10^{5}	_	A/W
		at 633 nm	_	4.1×10^{5}	_	_	4.1×10^{5}		A/W
		at 852 nm	_	3.5×10^{4}	_	_	3.5×10^4	_	A/W
Gain ^E				1.0×10^{7}	_	_	1.0×10^{7}	_	_
Anode Dark Current F	(After 30 min Storag	e in Darkness)	_	3	50	_	3	50	nA
ENI (Equivalent Noise	_	1.3×10^{-16}	_	_	1.3×10^{-16}		W		
	Anode Pulse Rise	e Time ^I	_	2.2	_	_	2.2		ns
Time Response E	Electron Transit T	ime ^J	_	22	_	_	22	_	ns
	Transit Time Spre	ad (TTS) ^K		1.2	_	_	1.2	_	ns
Anode Current Stability L	Light Hysteresis			0.1	_	_	0.1	_	%
Alloue Guiletti Stability	Voltage Hysteres	s	_	1.0	_	_	1.0	_	%

NOTES

- A: Averaged over any interval of 30 seconds maximum.
- B: The light source is a tungsten filament lamp operated at a distribution temperature of 2856K. Supply voltage is 100 V between the cathode and all other electrodes connected together as anode.
- C: Red/White ratio is the quotient of the cathode current measured using a red filter(Toshiba R-68) interposed between the light source and the tube by the cathode current measured with the filter removed under the same conditions as Note B.
- D:The value is cathode output current when a blue filter (Corning CS 5-58 polished to 1/2 stock thickness) is interposed between the light source and the tube under the same condition as Note B.
- E: Measured with the same light source as Note B and with the voltage distribution ratio shown in Table 1 below.

Table 1:Voltage Distribution Ratio

	Electrode	ŀ	〈	Dy	y1	Dy	2	Dy	/3	Dy	/4	Dy	/ 5	Dy	/6	Dy	7	Dy	/8	Dy	/9		Р
	Distribution Ratio		1			1	1		1			1	1		1			1		1	1	I	
Ī	Supply Voltage: 1000 V,								Ca	ath	od	le,		Dy	: E	Dyr	10	de,	,	P	: A	no	de

- F: Measured with the same supply voltage and voltage distribution ratio as Note E after removal of light.
- G:Measured at a supply voltage adjusted to provide an anode sensitivity of 100 A/lm.

H: ENI is an indication of the photon-limited signal-to-noise ratio. It refers to the amount of light in watts to produce a signal-to-noise ratio of unity in the output of a photomultiplier tube.

$$ENI = \frac{\sqrt{2q \cdot ldb \cdot G \cdot \Delta f}}{S}$$

where $q = Electronic charge (1.60 \times 10^{-19} coulomb)$.

Idb = Anode dark current(after 30 minute storage) in amperes.

G = Gain.

- Δf = Bandwidth of the system in hertz. 1 hertz is used.
- S = Anode radiant sensitivity in amperes per watt at the wavelength of peak response.
- I: The rise time is the time for the output pulse to rise from 10 % to 90 % of the peak amplitude when the entire photocathode is illuminated by a delta function light pulse.
- J: The electron transit time is the interval between the arrival of delta function light pulse at the entrance window of the tube and the time when the anode output reaches the peak amplitude. In measurement, the whole photocathode is illuminated.
- K: Also called transit time jitter. This is the fluctuation in electron transit time between individual pulses in the signal photoelectron mode, and may be defined as the FWHM of the frequency distribution of electron transit times.

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L: Hysteresis is temporary instability in anode current after light and voltage are applied.

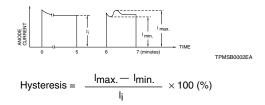


Figure 2: Anode Luminous Sensitivity and Gain Characteristics

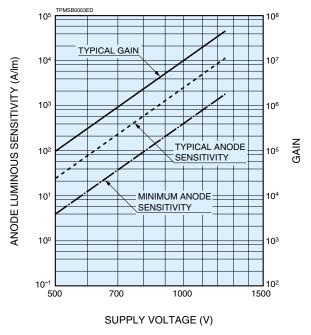
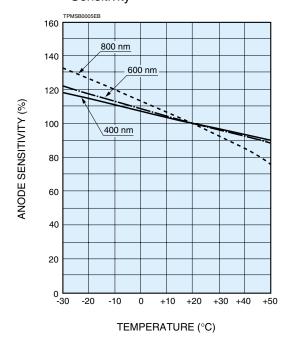


Figure 4: Typical Temperature Coefficient of Anode Sensitivity



(1)Light Hysteresis

The tube is operated at 750 V with an anode current of 1 μ A for 5 minutes. The light is then removed from the tube for a minute. The tube is then re-illuminated by the previous light level for a minute to measure the variation.

(2)Voltage Hysteresis

The tube is operated at 300 V with an anode current of 0.1 μ A for 5 minutes. The light is then removed from the tube and the supply voltage is quickly increased to 800 V. After a minute, the supply voltage is then reduced to the previous value and the tube is re-illuminated for a minute to measure the variation.

Figure 3: Typical Time Response

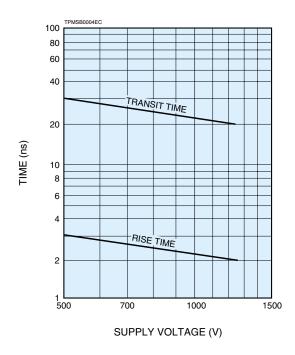
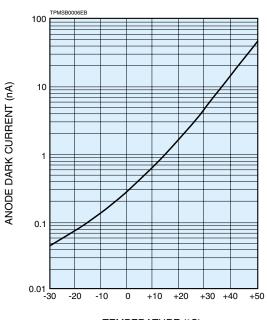


Figure 5: Typical Temperature Characteristic of Dark Current (at 1000 V, after 30 min storage in darkness)



TEMPERATURE (°C)

PHOTOMULTIPLIER TUBES R928, R955

Figure 6: Dimensional Outline and Basing Diagram (Unit: mm)

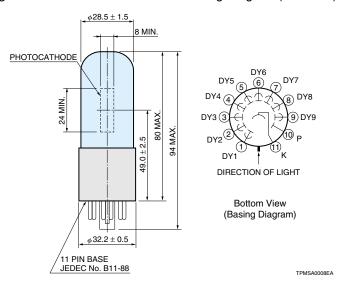
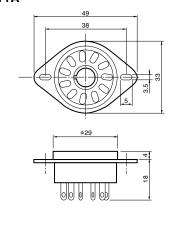


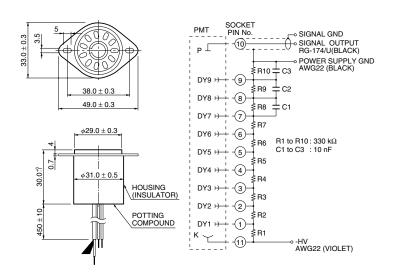
Figure 7: Socket (Unit: mm) Sold Separately

E678-11A

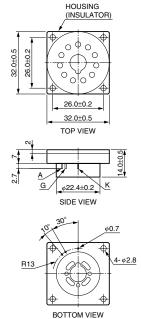


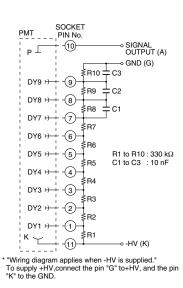
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Figure 8: D Type Socket Assembly (Unit: mm) Sold Separately **E717-63**



E717-74





Warning-Personal Safety Hazards

Electrical Shock–Operating voltages applied to this device present a shock hazard.

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^{*} Hamamatsu also provides C4900 series compact high voltage power supplies and C6270 series DP type socket assemblies which incorporate a DC to DC converter type high voltage power supply.